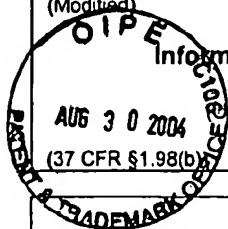


Substitute Form PTO-1449
(Modified)U.S. Department of Commerce
Patent and Trademark OfficeAttorney's Docket No.
16459-010001Application No.
10/724,029**Information Disclosure Statement
by Applicant**

(Use several sheets if necessary)

Applicant
Alexei A. ErchakFiling Date
November 26, 2003Group Art Unit
2879**U.S. Patent Documents**

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
<i>ME</i>	AA	6,091,085	07/18/00	Lester			02/19/98
	AB	6,469,324	10/22/02	Wang, Tien Yang			
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	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
	AQ	
	AR	
	AS	
	AT	

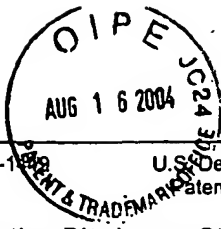
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11/09/04

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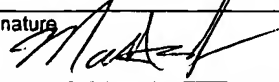


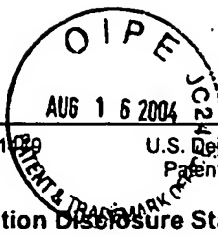
Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 16459-010001	Application No. 10/724,029
	Applicant Alexei A. Erchak		
	Filing Date November 26, 2003	Group Art Unit 2879	

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M	AA	5,359,345	10/25/94	Hunter et al.			
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							Yes	No
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	AQ	P.L. Gourley et al. "Optical properties of two-dimensional photonic lattices fabricated as honeycomb nanostructures in compound semiconductors", Appl. Phys. Lett. 64(6), February 7, 1994, pages 687-689
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EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	



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	Applicant Alexei A. Erchak		
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Other Documents (include Author, Title, Date, and Place of Publication)		
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